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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3480 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Super low on-state resistance:
 $R_{DS(on)1} = 31 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 25 \text{ A)}$
 $R_{DS(on)2} = 36 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 25 \text{ A)}$
- Low C_{iss} : $C_{iss} = 3600 \text{ pF TYP.}$
- Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

| | | | |
|--|----------------|-------------|------------------|
| Drain to Source Voltage ($V_{GS} = 0 \text{ V}$) | V_{DSS} | 100 | V |
| Gate to Source Voltage ($V_{DS} = 0 \text{ V}$) | V_{GSS} | ± 20 | V |
| Drain Current (DC) ($T_C = 25^\circ\text{C}$) | $I_{D(DC)}$ | ± 50 | A |
| Drain Current (pulse) ^{Note1} | $I_{D(pulse)}$ | ± 100 | A |
| Total Power Dissipation ($T_C = 25^\circ\text{C}$) | P_{T1} | 84 | W |
| Total Power Dissipation ($T_A = 25^\circ\text{C}$) | P_{T2} | 1.5 | W |
| Channel Temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |
| Single Avalanche Current ^{Note2} | I_{AS} | 34 | A |
| Single Avalanche Energy ^{Note2} | E_{AS} | 116 | mJ |

Notes 1. $PW \leq 10 \mu\text{s}$, Duty cycle $\leq 1\%$

2. Starting $T_{ch} = 25^\circ\text{C}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$

THERMAL RESISTANCE

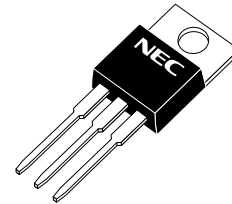
| | | | |
|--------------------|----------------|------|--------------------|
| Channel to Case | $R_{th(ch-C)}$ | 1.48 | $^\circ\text{C/W}$ |
| Channel to Ambient | $R_{th(ch-A)}$ | 83.3 | $^\circ\text{C/W}$ |

ORDERING INFORMATION

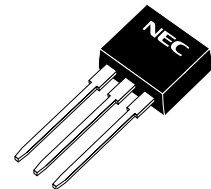
| PART NUMBER | PACKAGE |
|-------------|---------------------------|
| 2SK3480 | TO-220AB |
| 2SK3480-S | TO-262 |
| 2SK3480-ZJ | TO-263 |
| 2SK3480-Z | TO-220SMD ^{Note} |

Note TO-220SMD package is produced only in Japan.

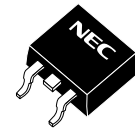
(TO-220AB)



(TO-262)



(TO-263, TO-220SMD)

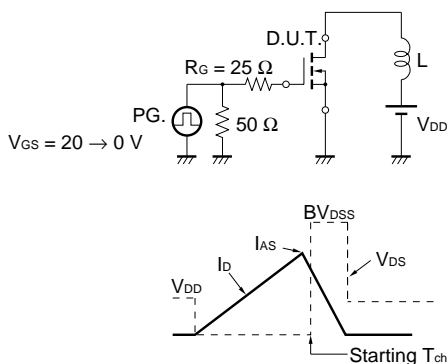


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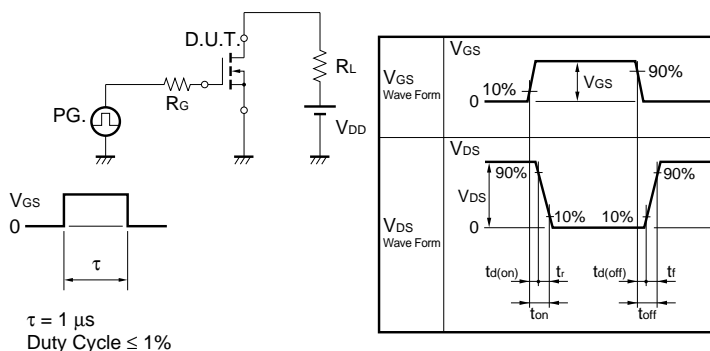
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------------------------------|---------------|---|------|------|----------|------------------|
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$ | | | 10 | μA |
| Gate Leakage Current | I_{GSS} | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$ | | | ± 10 | μA |
| Gate Cut-off Voltage | $V_{GS(off)}$ | $V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$ | 1.5 | 2.0 | 2.5 | V |
| Forward Transfer Admittance | $ y_{fs} $ | $V_{DS} = 10\text{ V}, I_D = 25\text{ A}$ | 17 | 34 | | S |
| Drain to Source On-state Resistance | $R_{DS(on)1}$ | $V_{GS} = 10\text{ V}, I_D = 25\text{ A}$ | | 25 | 31 | $\text{m}\Omega$ |
| | $R_{DS(on)2}$ | $V_{GS} = 4.5\text{ V}, I_D = 25\text{ A}$ | | 27 | 36 | $\text{m}\Omega$ |
| Input Capacitance | C_{iss} | $V_{DS} = 10\text{ V}$ | | 3600 | | pF |
| Output Capacitance | C_{oss} | $V_{GS} = 0\text{ V}$ | | 360 | | pF |
| Reverse Transfer Capacitance | C_{rss} | $f = 1\text{ MHz}$ | | 190 | | pF |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD} = 50\text{ V}, I_D = 25\text{ A}$ | | 15 | | ns |
| Rise Time | t_r | $V_{GS} = 10\text{ V}$ | | 11 | | ns |
| Turn-off Delay Time | $t_{d(off)}$ | $R_G = 0\ \Omega$ | | 68 | | ns |
| Fall Time | t_f | | | 6.0 | | ns |
| Total Gate Charge | Q_G | $V_{DD} = 80\text{ V}$ | | 74 | | nC |
| Gate to Source Charge | Q_{GS} | $V_{GS} = 10\text{ V}$ | | 10 | | nC |
| Gate to Drain Charge | Q_{GD} | $I_D = 50\text{ A}$ | | 20 | | nC |
| Body Diode Forward Voltage | $V_{F(S-D)}$ | $I_F = 50\text{ A}, V_{GS} = 0\text{ V}$ | | 1.0 | | V |
| Reverse Recovery Time | t_{rr} | $I_F = 50\text{ A}, V_{GS} = 0\text{ V}$ | | 70 | | ns |
| Reverse Recovery Charge | Q_{rr} | $di/dt = 100\text{ A}/\mu\text{s}$ | | 180 | | nC |

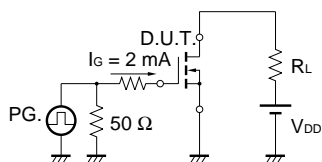
TEST CIRCUIT 1 AVALANCHE CAPABILITY



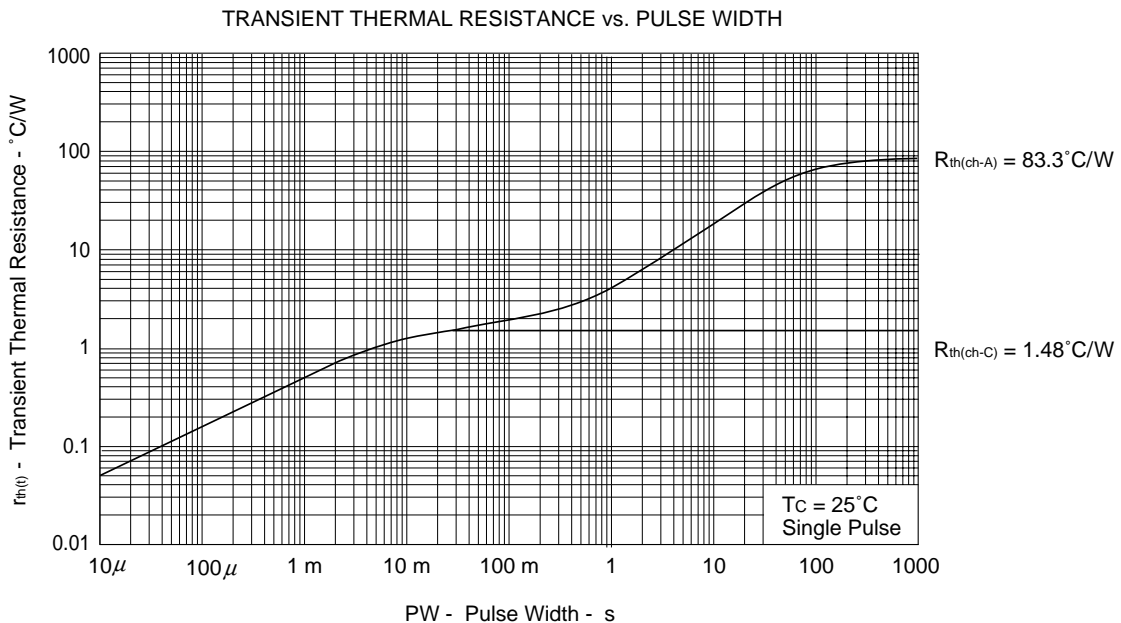
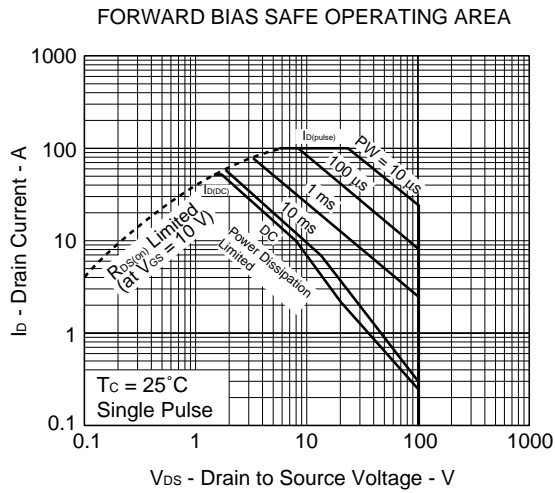
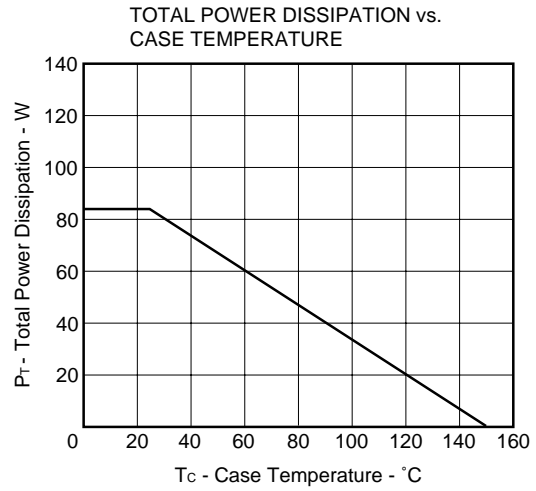
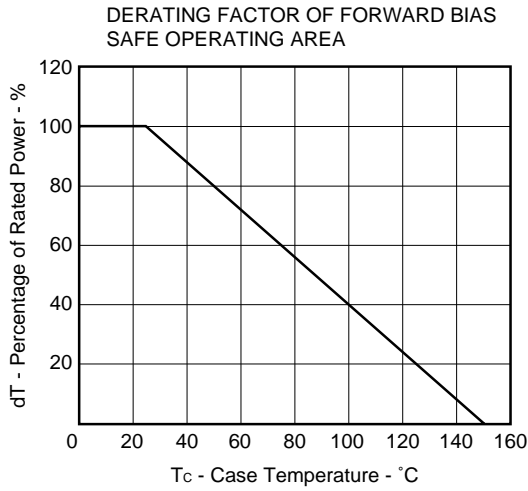
TEST CIRCUIT 2 SWITCHING TIME



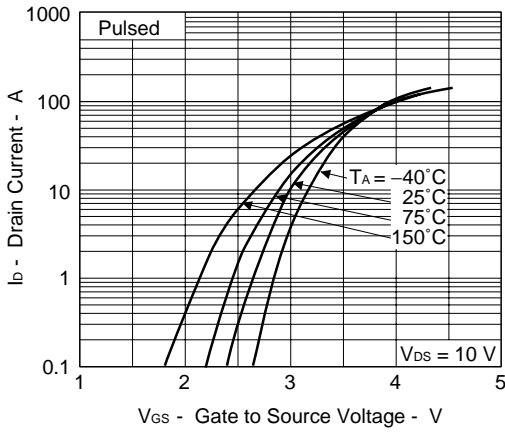
TEST CIRCUIT 3 GATE CHARGE



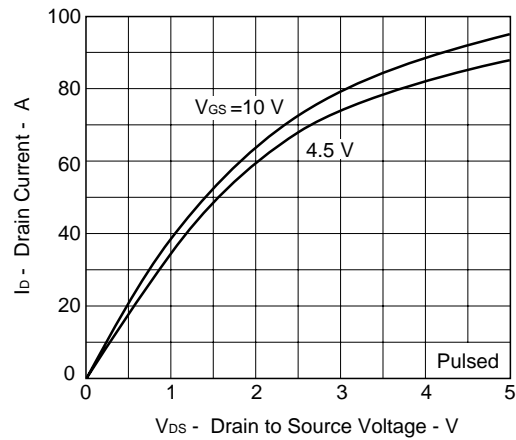
TYPICAL CHARACTERISTICS (T_A = 25°C)



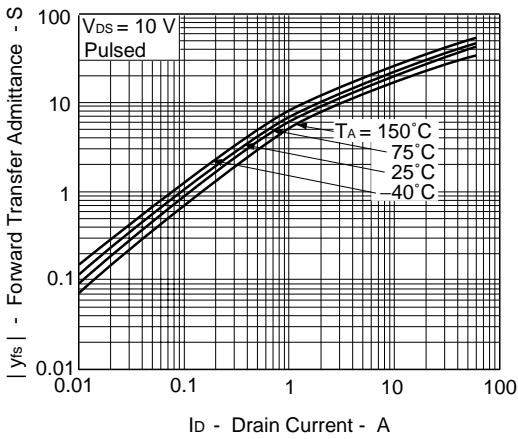
FORWARD TRANSFER CHARACTERISTICS



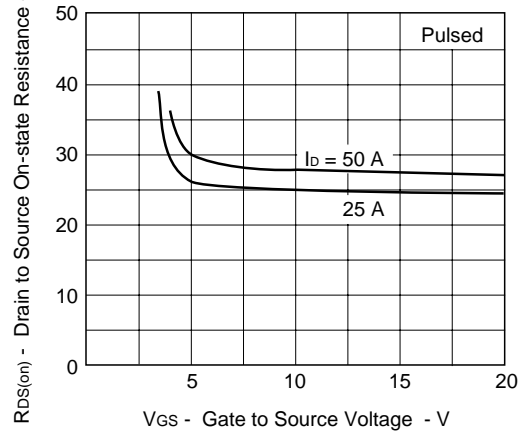
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



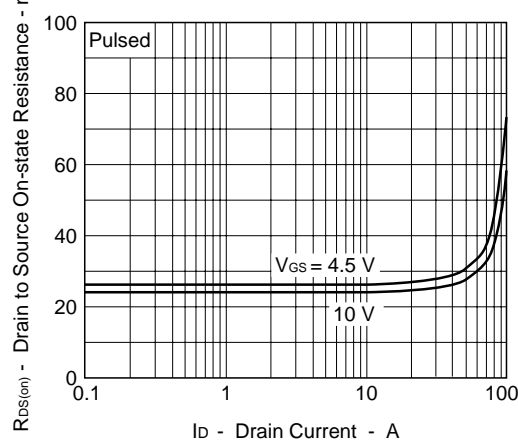
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



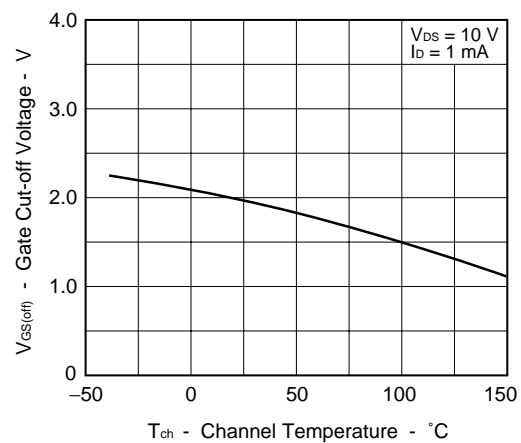
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



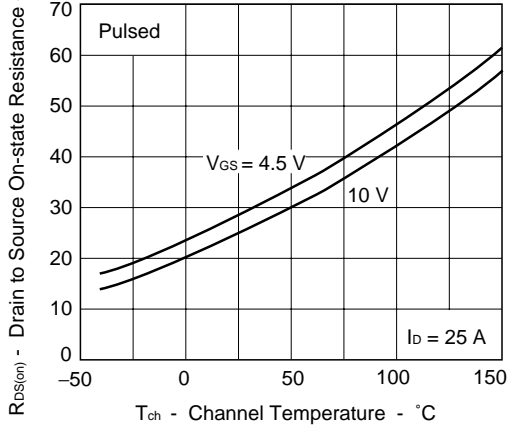
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



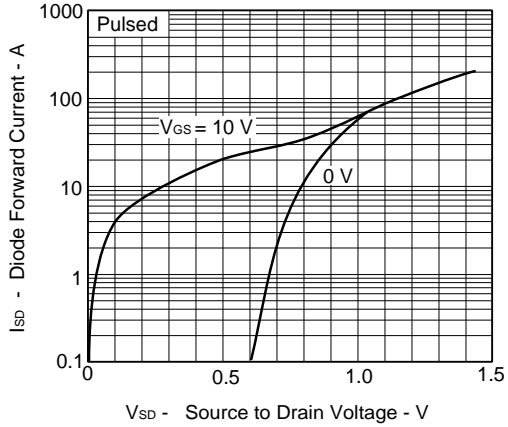
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



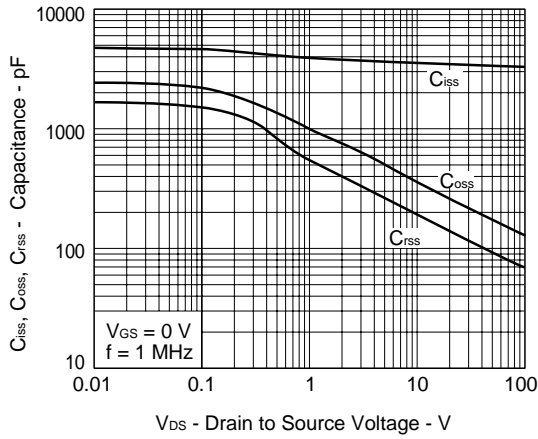
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



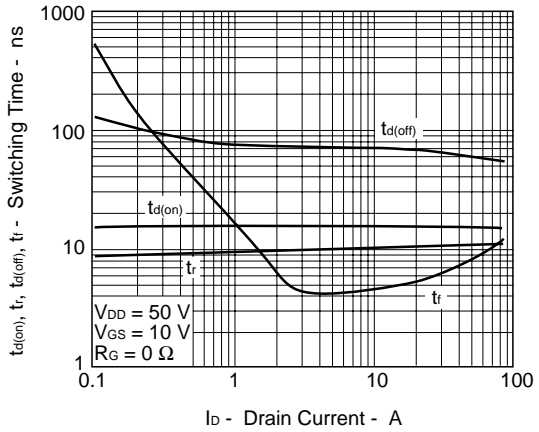
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



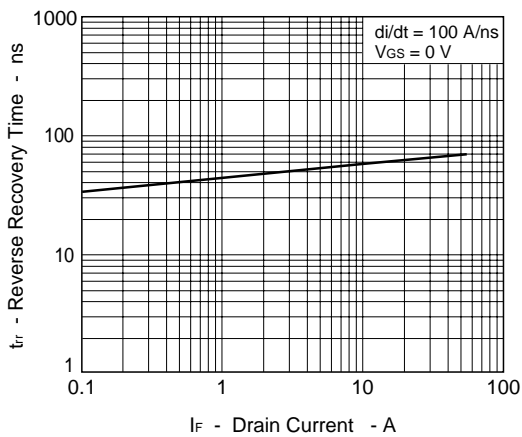
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



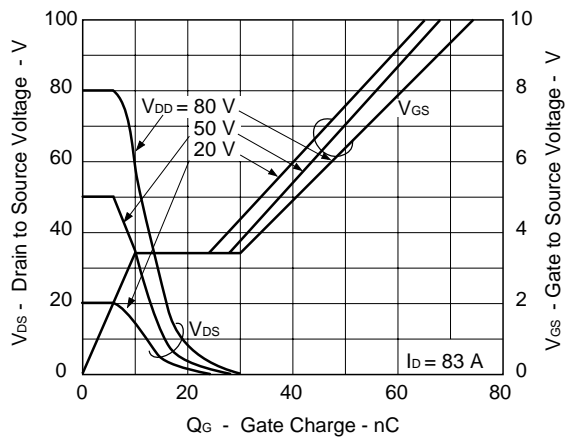
SWITCHING CHARACTERISTICS

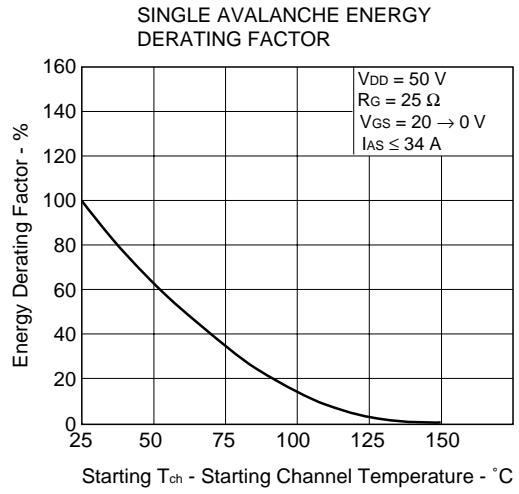
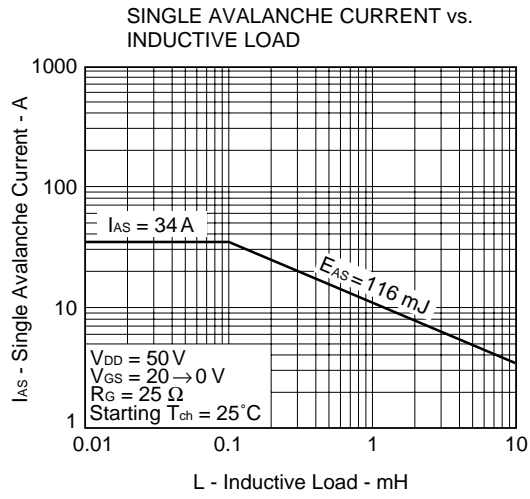


REVERSE RECOVERY TIME vs. DRAIN CURRENT



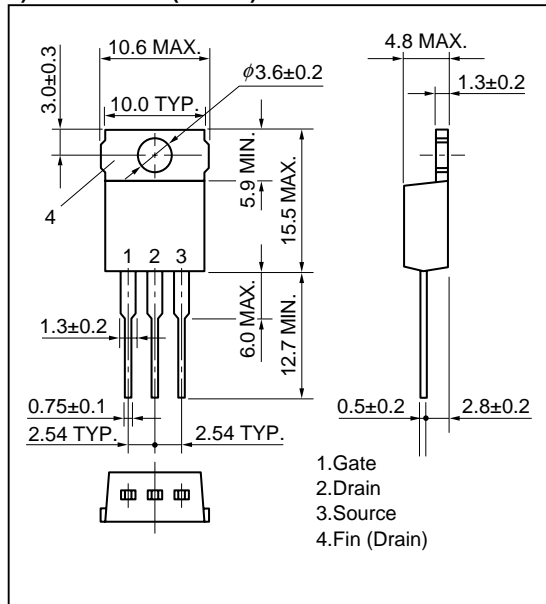
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



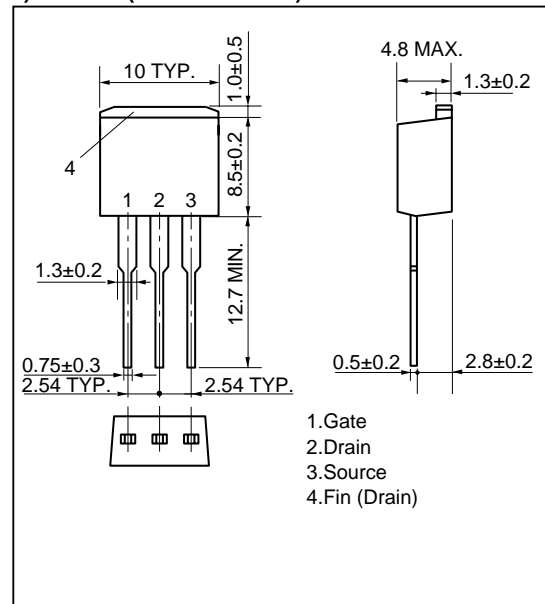


PACKAGE DRAWINGS (Unit: mm)

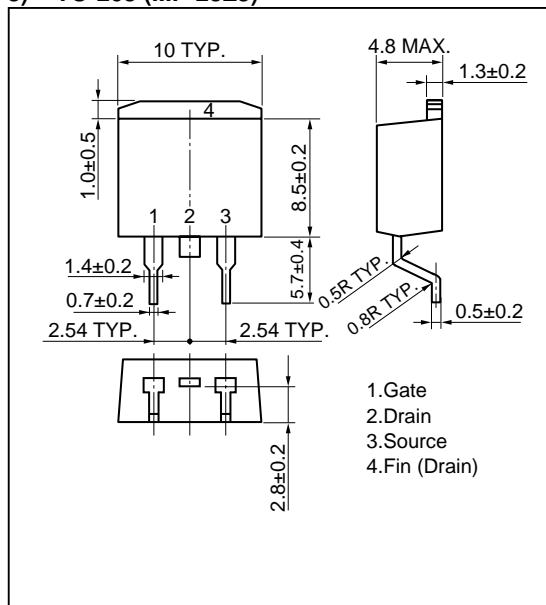
1) TO-220AB(MP-25)



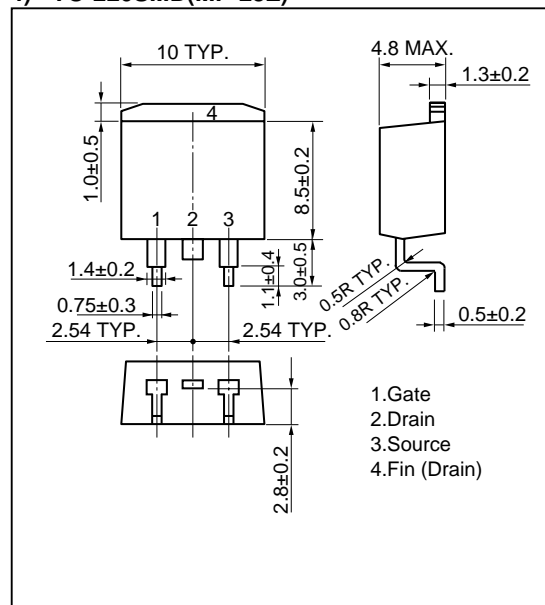
2) TO-262(MP-25 Fin Cut)



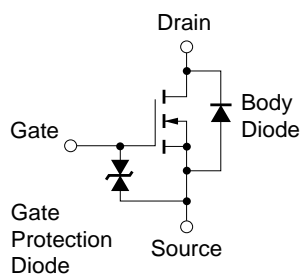
3) TO-263 (MP-25ZJ)



4) TO-220SMD(MP-25Z)^{Note}



EQUIVALENT CIRCUIT



Note This package is produced only in Japan.

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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